# **Triple Line Receiver**

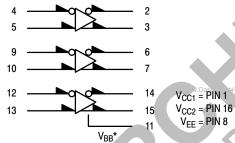
The MC10116 is a triple differential amplifier designed for use in sensing differential signals over long lines. The base bias supply (VBB) is made available at pin 11 to make the device useful as a Schmitt trigger, or in other applications where a stable reference voltage is necessary.

Active current sources provide the MC10116 with excellent common mode noise rejection. If any amplifier in a package is not used, one input of that amplifier must be connected to V<sub>BB</sub> (pin 11) to prevent upsetting the current source bias network.

Complementary outputs are provided to allow driving twisted pair lines, to enable cascading of several amplifiers in a chain, or simply to provide complement outputs of the input logic function.

- $P_D = 85 \text{ mW typ/pkg (No Load)}$
- $t_{pd} = 2.0 \text{ ns typ}$
- $t_r$ ,  $t_f = 2.0$  ns typ (20%–80%)

# LOGIC DIAGRAM



V<sub>EE</sub> = PIN 8

When the input pin with the bubble goes positive, the output pin with the bubble goes positive.

# DIP **PIN ASSIGNMENT**



Pin assignment is for Dual-in-Line Package. For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



# ON Semiconductor

http://onsemi.com

# **MARKING DIAGRAMS**



CDIP-16 **L SUFFIX CASE 620** 





PDIP-16 P SUFFIX **CASE 648** 





PLCC-20 **FN SUFFIX CASE 775** 



= Assembly Location

WL = Wafer Lot YY = Year WW = Work Week

#### ORDERING INFORMATION

Device	Package	Shipping
MC10116L	CDIP-16	25 Units / Rail
MC10116P	PDIP-16	25 Units / Rail
MC10116FN	PLCC-20	46 Units / Rail

<sup>\*</sup>V<sub>BB</sub> to be used to supply bias to the MC10116 only and bypassed (when used) with 0.01  $\mu F$  to 0.1  $\mu F$  capacitor to ground (0 V).  $V_{BB}$  can source < 1.0 mA.

### **ELECTRICAL CHARACTERISTICS**

		<b>-</b> .		Test Limits		3				
		Pin Under	-30	0°C		+25°C		+85	5°C	
Characteristic	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Un
Power Supply Drain Current	Ι <sub>Ε</sub>	8		23		17	21		23	mAd
Input Current	I <sub>inH</sub>	4		150			95		95	μΑσ
	I <sub>CBO</sub>	4		1.5			1.0		1.0	μΑσ
Output Voltage Logic 1	V <sub>OH</sub>	2 3	-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vd
Output Voltage Logic 0	V <sub>OL</sub>	2 3	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	Vd
Threshold Voltage Logic 1	V <sub>OHA</sub>	2 3	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		Vd
Threshold Voltage Logic 0	V <sub>OLA</sub>	2 3		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vd
Reference Voltage	$V_{BB}$	11	-1.420	-1.280	-1.350		-1.230	-1.295	-1.150	Vd
Switching Times (50Ω Load)										ns
Propagation Delay	t <sub>4+2+</sub> t <sub>4-2-</sub> t <sub>4+3-</sub> t <sub>4-3+</sub>	2 2 3 3	1.0 1.0 1.0 1.0	3.1 3.1 3.1 3.1	1.0 1.0 1.0 1.0	2.0 2.0 2.0 2.0 2.0	2.9 2.9 2.9 2.9	1.0 1.0 1.0 1.0	3.3 3.3 3.3 3.3	
Rise Time (20 to 80%)	t <sub>2+</sub> t <sub>3+</sub>	2 3	1.1 1.1	3.6 3.6	1.1 1.1	2.0 2.0	3.3 3.3	1.1 1.1	3.7 3.7	
Fall Time (20 to 80%)		2	1.1	3.6	1.1	2.0	3.3	1.1	3.7	
(20 to 6076)	t <sub>2-</sub> t <sub>3-</sub>	2	111	2.6	1.1	2.0	3.3	1.1	3.7	

# **ELECTRICAL CHARACTERISTICS** (continued)

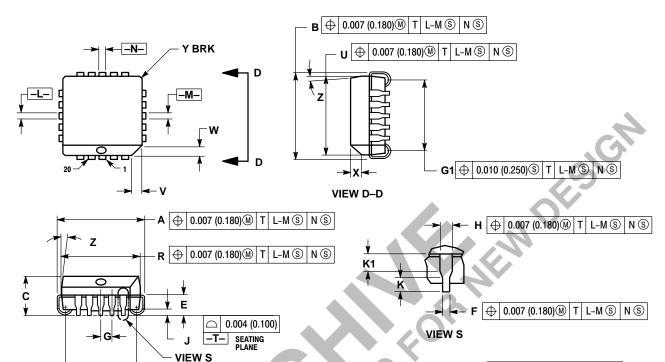
				TEST VOLTAGE VALUES (Volts)						
@ Test Temperature			V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>BB</sub>	V <sub>EE</sub>		
–30°C			-0.890	-1.890	-1.205	-1.500	From	-5.2		
	+25°C			-0.810	-1.850	-1.105	-1.475	Pin	-5.2	
+85°C			-0.700	-1.825	-1.035	-1.440	11	<b>-</b> 5.2		
			Pin	TES	T VOLTA	SE APPLIED	TO PINS L	ISTED BEL	.ow	
Characteri	stic	Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>BB</sub>	V <sub>EE</sub>	(V <sub>CC</sub> ) Gnd
Power Supply Drain C	Current	ΙE	8		4, 9, 12			5, 10, 13	8	1, 16
Input Current		I <sub>inH</sub>	4	4	9, 12			5, 10, 13	8	1, 16
		I <sub>CBO</sub>	4		9, 12			5, 10, 13	8,4	1, 16
Output Voltage	Logic 1	V <sub>OH</sub>	2 3	4 9, 12	9, 12 4			5, 10, 13 5, 10, 13	8	1, 16 1, 16
Output Voltage	Logic 0	V <sub>OL</sub>	2 3	9, 12 4	4 9, 12			5, 10, 13 5, 10, 13	8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V <sub>OHA</sub>	2 3	9, 12	9, 12	4	4	5, 10, 13 5, 10, 13	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	V <sub>OLA</sub>	2 3	9, 12	9, 12	4	4	5, 10, 13 5, 10, 13	8 8	1, 16 1, 16
Reference Voltage		V <sub>BB</sub>	11					5, 10, 13	8	1, 16
Switching Times	(50Ω Load)					Pulse In	Pulse Out		-3.2 V	+2.0 V
Propagation Delay		t <sub>4+2+</sub> t <sub>4-2-</sub> t <sub>4+3-</sub> t <sub>4-3+</sub>	2 2 3 3			4 4 4 4	2 2 3 3	5, 10, 13 5, 10, 13 5, 10, 13 5, 10, 13	8 8 8 8	1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t <sub>2+</sub> t <sub>3+</sub>	2 3			4 4	2 3	5, 10, 13 5, 10, 13	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t <sub>2-</sub> t <sub>3-</sub>	2 3		0	4 4	2 3	5, 10, 13 5, 10, 13	8 8	1, 16 1, 16

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

#### PACKAGE DIMENSIONS

# PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



#### NOTES:

G1 ⊕ 0.010 (0.250)③ T L-M ⑤ N ⑤

OF MICE. NOT PERSON

- OTES:

  1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.

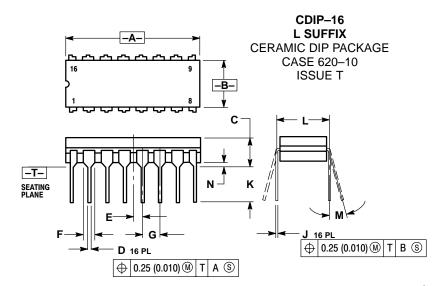
  2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

  3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.

  4. DIMENSIONING AND TOLERANCING PER ANSI V14 5M 1982
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
C	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
ſ	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
c	0.350	0.356	8.89	9.04
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
Χ	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2°	10°	2 °	10°
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

### PACKAGE DIMENSIONS



#### NOTES:

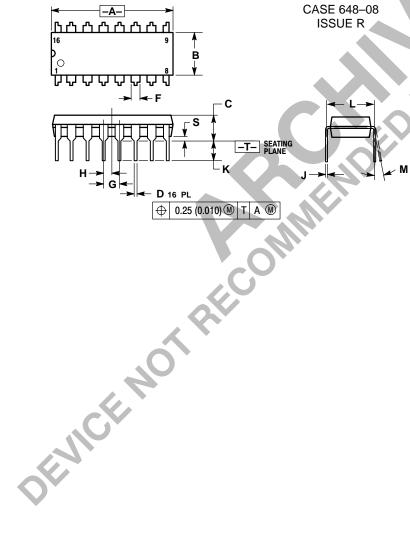
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: INCH.
   DIMENSION LTO CENTER OF LEAD WHEN CONTROLLING DIMENSION LTO CENTER OF LEAD WHEN

- FORMED PARALLEL

  DIMENSION F MAY NARROW TO 0.76 (0.030)
  WHERE THE LEAD ENTERS THE CERAMIC
  BODY.

	INC	HES	MILLIMETERS			
DIM	MIN MAX		MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015	0.020	0.39	0.50		
Е	0.050	BSC	1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100	BSC	2.54	BSC		
Н	0.008	0.015	0.21	0.38		
K	0.125	0.170	3.18	4.31		
L	0.300	BSC	7.62 BSC			
M	0 °	15°	0 °	15°		
N	0.020	0.040	0.51	1.01		





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
C	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27	BSC	
J	0.008	0.015	0.21	0.38	
K	0.110	0.110 0.130		3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	

# **Notes**



# **Notes**





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